
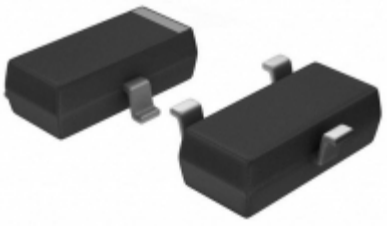
	<p><b>SI2319DDS-T1-GE3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SI2319DDS-T1-GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CHAN 40V</p> <p><b>Datenblätter:</b>  <a href="#">SI2319DDS-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 9000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI2319DDS-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CHAN 40V
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	9000 pcs Stock
Hersteller Standard Vorlaufzeit	32 Weeks
detaillierte Beschreibung	P-Channel 40V 2.7A (Ta), 3.6A (Tc) 1W (Ta), 1.7W
Serie	TrenchFET® Gen III
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1W (Ta), 1.7W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.7A (Ta), 3.6A (Tc)
Rds On (Max) @ Id, Vgs	75 mOhm @ 2.7A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	650pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2319DDS-T1-GE3TR















































SI2319DDS-T1-GE3 ist neu im Original. Suche SI2319DDS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2319DDS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2319DDS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SI2319CDS-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 40V 4.4A SOT-23</p>	 <p><b>SI2319DS</b> 89K SI2319DS 89K</p>	 <p><b>SI2319DS-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 40V 2.3A SOT23-3</p>	 <p><b>SI2319ADS-T1-GE3</b> V SI2319ADS-T1-GE3 V</p>
 <p><b>SI2319C95TF</b> Original SI2319C95TF Original</p>	 <p><b>SI2319CDS-T1-E3</b> VISHAY SI2319CDS-T1-E3 VISHAY</p>	 <p><b>SI2319DS-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 40V 2.3A SOT23-3</p>	 <p><b>SI2319DS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 40V 2.3A SOT23-3</p>

### heiße Teile

Mehr

 SI2316BDS-T1-GE3	 SI2316BDS-T1-GE3	 SI2316DS	 SI2316DS-T1-E3	 SI2316DS-T1-E3
 SI2316DS-T1-GE3	 SI2316DS-T1-GE3	 SI2317DS	 SI2317DS-T1-E3	 SI2318ADS-T1-GE3
 SI2318BDS-T1-E3	 SI2318BDS-T1-GE3	 SI2318CDS-T1-E3	 SI2318CDS-T1-GE3	 SI2318CDS-T1-GE3
 SI2318DS	 SI2318DS-T1-E3	 SI2318DS-T1-GE3	 SI2318DS-T1-GE3	 SI2318DS-T1-GE3
 SI2319ADS-T1-GE3	 SI2319C95TF	 SI2319CDS-T1-E3	 SI2319CDS-T1-GE3	 SI2319CDS-T1-GE3
 SI2319DS	 SI2319DS-T1-E3	 SI2319DS-T1-E3	 SI2319DS-T1-GE3	 SI2319DS-T1-GE3
 SI2320DS	 SI2320DS-T1-E3	 SI2320DS-T1-GE3	 SI2321DS-T1-E3	 SI2321DS-T1-E3
 SI2321DS-T1-GE3	 SI2321DS-T1-GE3	 SI2323CDS-T1	 SI2323CDS-T1-GE3	 SI2323CDS-T1-GE3
 SI2323CDS-T1-GE3	 SI2323DDS-T1-E3	 SI2323DDS-T1-GE3	 SI2323DDS-T1-GE3	 SI2323DS
 SI2323DS-T1-E3	 SI2323DS-T1-E3	 SI2323DS-T1-GE3	 SI2323DS-T1-GE3	 SI2324DS-T1-E3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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